

8-BIT PARALLEL-IN/SERIAL-OUT SHIFT REGISTER

FEATURES

- Asynchronous 8-bit parallel load
- Synchronous serial input
- Output capability: standard
- I^{CC} category: MSI

GENERAL DESCRIPTION

The 74HC/HCT165 are high-speed Si-gate CMOS devices and are pin compatible with low power Schottky TTL (LS TTL). They are specified in compliance with JEDEC standard no. 7A.

The 74HC/HCT165 are 8-bit parallel-load or serial-in shift registers with complementary serial outputs (Q_7 and \bar{Q}_7) available from the last stage. When the parallel load (\overline{PL}) input is LOW, parallel data from the D_0 to D_7 inputs are loaded into the register asynchronously.

When \overline{PL} is HIGH, data enters the register serially at the D_s input and shifts one place to the right ($Q_0 \rightarrow Q_1 \rightarrow Q_2$, etc.) with each positive-going clock transition. This feature allows parallel-to-serial converter expansion by tying the Q_7 output to the D_s input of the succeeding stage.

The clock input is a gated-OR structure which allows one input to be used as an active LOW clock enable (\overline{CE}) input. The pin assignment for the CP and \overline{CE} inputs is arbitrary and can be reversed for layout convenience. The LOW-to-HIGH transition of input \overline{CE} should only take place while CP HIGH for predictable operation. Either the CP or the \overline{CE} should be HIGH before the LOW-to-HIGH transition of \overline{PL} to prevent shifting the data when \overline{PL} is activated.

APPLICATIONS

- Parallel-to-serial data conversion

SYMBOL	PARAMETER	CONDITIONS	TYPICAL		UNIT
			HC	HCT	
t_{PHL}/t_{PLH}	propagation delay CP to Q_7 , \bar{Q}_7 \overline{PL} to Q_7 , \bar{Q}_7 D_7 to Q_7 , \bar{Q}_7	$C_L = 15 \text{ pF}$ $V_{CC} = 5 \text{ V}$	16	14	ns
			15	17	ns
			11	11	ns
f_{max}	maximum clock frequency		56	48	MHz
C_I	input capacitance		3.5	3.5	pF
C_{PD}	power dissipation capacitance per package	notes 1 and 2	35	35	pF

GND = 0 V; $T_{amb} = 25^\circ\text{C}$; $t_r = t_f = 6 \text{ ns}$

Notes

1. C_{PD} is used to determine the dynamic power dissipation (P_D in μW):

$$P_D = C_{PD} \times V_{CC}^2 \times f_i + \sum (C_L \times V_{CC}^2 \times f_o) \text{ where:}$$

f_i = input frequency in MHz C_L = output load capacitance in pF
 f_o = output frequency in MHz V_{CC} = supply voltage in V
 $\sum (C_L \times V_{CC}^2 \times f_o)$ = sum of outputs

2. For HC the condition is $V_I = \text{GND to } V_{CC}$
 For HCT the condition is $V_I = \text{GND to } V_{CC} - 1.5 \text{ V}$

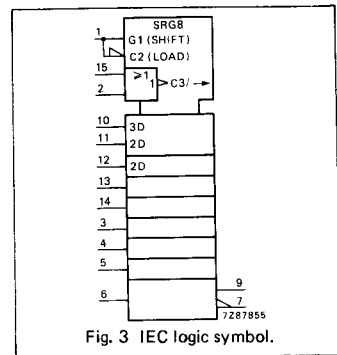
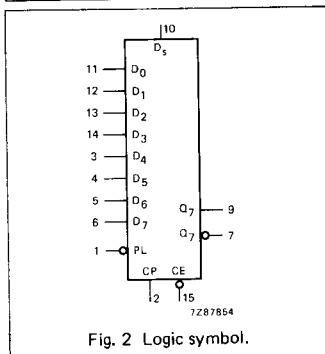
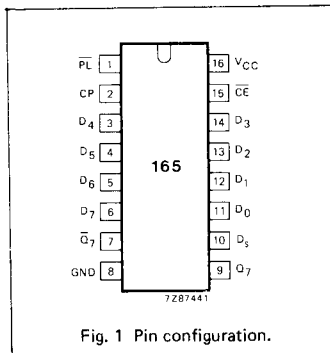
PACKAGE OUTLINES

16-lead DIL; plastic (SOT38Z).

16-lead mini-pack; plastic (SO16; SOT109A).

PIN DESCRIPTION

PIN NO.	SYMBOL	NAME AND FUNCTION
1	\overline{PL}	asynchronous parallel load input (active LOW)
7	\bar{Q}_7	complementary output from the last stage
9	Q_7	serial output from the last stage
2	CP	clock input (LOW-to-HIGH edge-triggered)
8	GND	ground (0 V)
10	D_s	serial data input
11, 12, 13, 14, 3, 4, 5, 6	D_0 to D_7	parallel data inputs
15	\overline{CE}	clock enable input (active LOW)
16	V_{CC}	positive supply voltage



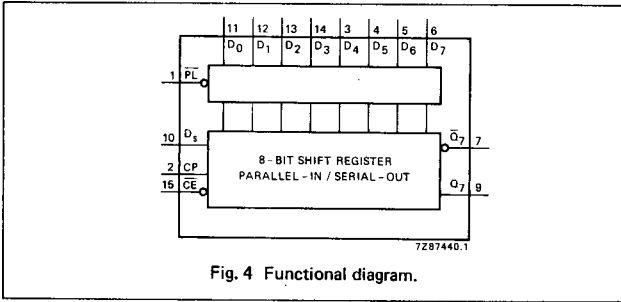


Fig. 4 Functional diagram.

FUNCTION TABLE

OPERATING MODES	INPUTS					Q _n REGISTERS		OUTPUTS	
	PL	CE	CP	D _s	D ₀ -D ₇	Q ₀	Q ₁ -Q ₆	Q ₇	Q̄ ₇
parallel load	L	X	X	X	L	L	L - L H - H	L	H
serial shift	H	L	↑	l	X	L	Q ₀ -Q ₅ Q ₀ -Q ₅	Q ₆ Q ₆	Q̄ ₆ Q̄ ₆
hold "do nothing"	H	H	X	X	X	Q ₀	Q ₁ -Q ₆	Q ₇	Q ₇

H = HIGH voltage level
h = HIGH voltage level one set-up time prior to the LOW-to-HIGH clock transition
L = LOW voltage level
l = LOW voltage level one set-up time prior to the LOW-to-HIGH clock transition
q = lower case letters indicate the state of the referenced output one set-up time prior to the LOW-to-HIGH clock transition
X = don't care
↑ = LOW-to-HIGH clock transition

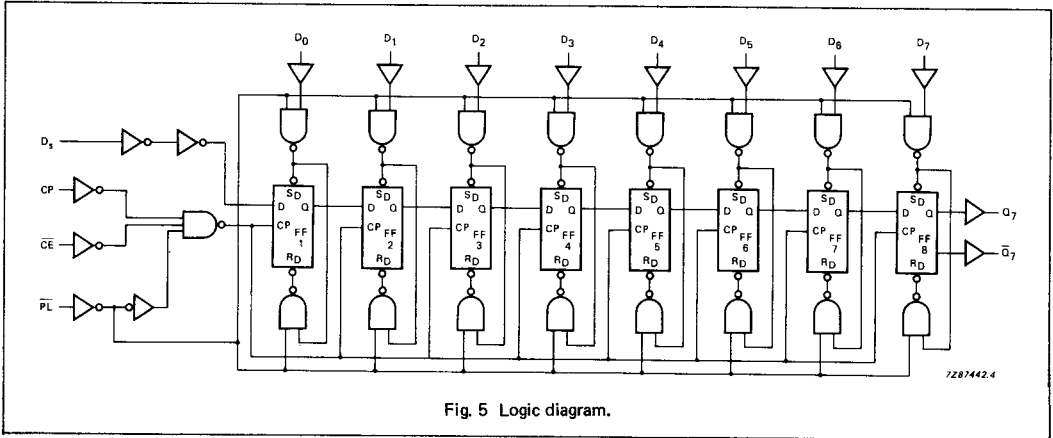


Fig. 5 Logic diagram.

DC CHARACTERISTICS FOR 74HC

For the DC characteristics see chapter "HCMOS family characteristics", section "Family specifications".

Output capability: standard
I_{CC} category: MSI

AC CHARACTERISTICS FOR 74HC

GND = 0 V; $t_r = t_f = 6$ ns; $C_L = 50$ pF

SYMBOL	PARAMETER	T_{amb} (°C)						UNIT	TEST CONDITIONS		
		74HC							V_{CC} V	WAVEFORMS	
		+25			-40 to +85		-40 to +125				
		min.	typ.	max.	min.	max.	min.				max.
t_{PHL}/t_{PLH}	propagation delay \overline{CE} , CP to Q_7 , \overline{Q}_7		52 19 15	165 33 28		205 41 35		250 50 43	ns	2.0 4.5 6.0	Fig. 6
t_{PHL}/t_{PLH}	propagation delay PL to Q_7 , \overline{Q}_7		50 18 14	165 33 28		205 41 35		250 50 43	ns	2.0 4.5 6.0	Fig. 7
t_{PHL}/t_{PLH}	propagation delay D_7 to Q_7 , \overline{Q}_7		36 13 10	120 24 20		150 30 26		180 36 31	ns	2.0 4.5 6.0	Fig. 8
t_{THL}/t_{TLH}	output transition time		19 7 6	75 15 13		95 19 16		110 22 19	ns	2.0 4.5 6.0	Fig. 6
t_W	clock pulse width HIGH or LOW	80 16 14	17 6 5		100 20 17		120 24 20		ns	2.0 4.5 6.0	Fig. 6
t_W	parallel load pulse width; LOW	80 16 14	14 5 4		100 20 17		120 24 20		ns	2.0 4.5 6.0	Fig. 7
t_{rem}	removal time PL to CP, \overline{CE}	100 20 17	22 8 6		125 25 21		150 30 26		ns	2.0 4.5 6.0	Fig. 7
t_{su}	set-up time D_s to CP, \overline{CE}	80 16 14	11 4 3		100 20 17		120 24 20		ns	2.0 4.5 6.0	Fig. 9
t_{su}	set-up time \overline{CE} to CP; CP to \overline{CE}	80 16 14	17 6 5		100 20 17		120 24 20		ns	2.0 4.5 6.0	Fig. 9
t_{su}	set-up time D_n to PL	80 16 14	22 8 6		100 20 17		120 24 20		ns	2.0 4.5 6.0	Fig. 10
t_h	hold time D_s to CP, \overline{CE} D_n to PL	5 5 5	6 2 2		5 5 5		5 5 5		ns	2.0 4.5 6.0	Fig. 9
t_h	hold time \overline{CE} to CP CP to \overline{CE}	5 5 5	-17 -6 -5		5 5 5		5 5 5		ns	2.0 4.5 6.0	Fig. 9
f_{max}	maximum clock pulse frequency	6 30 35	17 51 61		5 24 28		4 20 24		MHz	2.0 4.5 6.0	Fig. 6

DC CHARACTERISTICS FOR 74HCT

For the DC characteristics see chapter "HCMOS family characteristics", section "Family specifications".

Output capability: standard

I_{CC} category: MSI

Note to HCT types

The value of additional quiescent supply current (ΔI_{CC}) for a unit load of 1 is given in the family specifications. To determine ΔI_{CC} per input, multiply this value by the unit load coefficient shown in the table below.

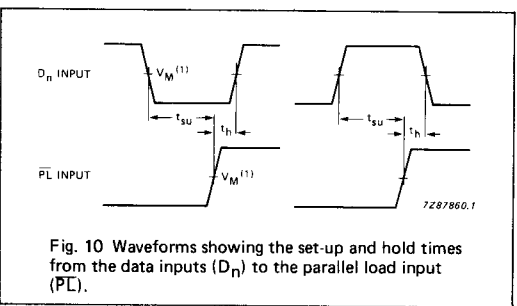
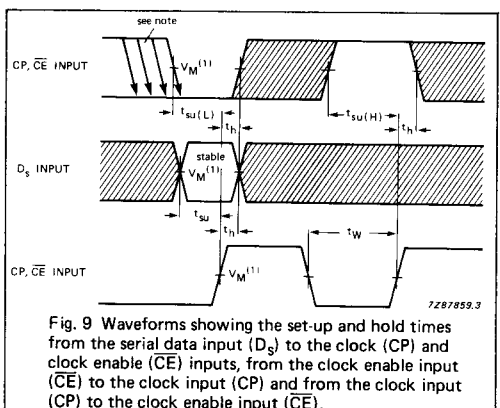
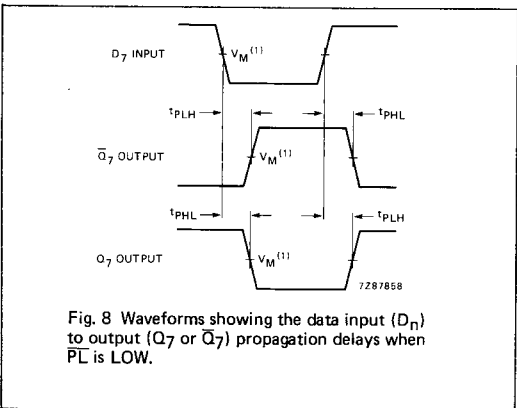
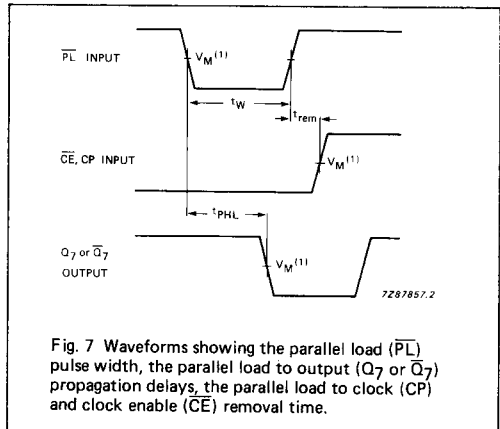
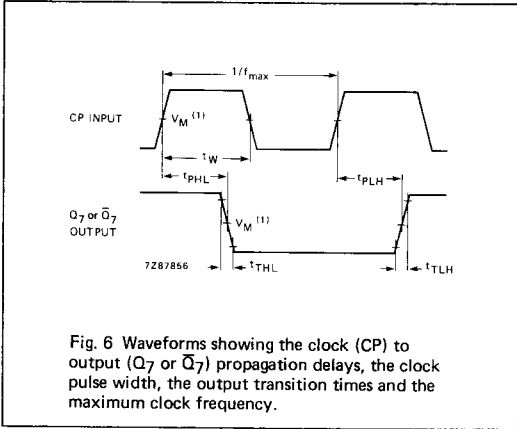
INPUT	UNIT LOAD COEFFICIENT
D_n	0.35
D_s	0.35
C_P	0.65
\overline{CE}	0.65
\overline{PL}	0.65

AC CHARACTERISTICS FOR 74HCT

GND = 0 V; $t_r = t_f = 6$ ns; $C_L = 50$ pF

SYMBOL	PARAMETER	T _{amb} (°C)						UNIT	TEST CONDITIONS		
		74HCT							V _{CC} V	WAVEFORMS	
		+25			-40 to +85		-40 to +125				
		min.	typ.	max.	min.	max.	min.				max.
t _{PHL} / t _{PLH}	propagation delay CE, CP to Q ₇ , Q ₇		17	34		43		51	ns	4.5	Fig. 6
t _{PHL} / t _{PLH}	propagation delay PL to Q ₇ , Q ₇		20	40		50		60	ns	4.5	Fig. 7
t _{PHL} / t _{PLH}	propagation delay D ₇ to Q ₇ , Q ₇		14	28		35		42	ns	4.5	Fig. 8
t _{THL} / t _{TLH}	output transition time		7	15		19		22	ns	4.5	Fig. 6
t _W	clock pulse width HIGH or LOW	16	6		20		24		ns	4.5	Fig. 6
t _W	parallel load pulse width; LOW	20	9		25		30		ns	4.5	Fig. 7
t _{rem}	removal time PL to CP, CE	20	8		25		30		ns	4.5	Fig. 7
t _{su}	set-up time D _s to CP, CE	20	2		25		30		ns	4.5	Fig. 9
t _{su}	set-up time CE to CP; CP to CE	20	7		25		30		ns	4.5	Fig. 9
t _{su}	set-up time D _n to PL	20	10		25		30		ns	4.5	Fig. 10
t _h	hold time D _s to CP, CE; D _n to PL	7	-1		9		11		ns	4.5	Fig. 9
t _h	hold time CE to CP, CP to CE	0	-7		0		0		ns	4.5	Fig. 9
f _{max}	maximum clock pulse frequency	26	44		21		17		MHz	4.5	Fig. 6

AC WAVEFORMS



Note to Figs 6 and 7
The changing to output assumes internal Q₆ opposite state from Q₇.

Note to Fig. 9
 \bar{CE} may change only from HIGH-to-LOW while CP is LOW.
The shaded areas indicate when the input is permitted to change for predictable output performance.

Note to AC waveforms

- (1) HC : $V_M = 50\%$; $V_I = \text{GND to } V_{CC}$.
- HCT: $V_M = 1.3 \text{ V}$; $V_I = \text{GND to } 3 \text{ V}$.